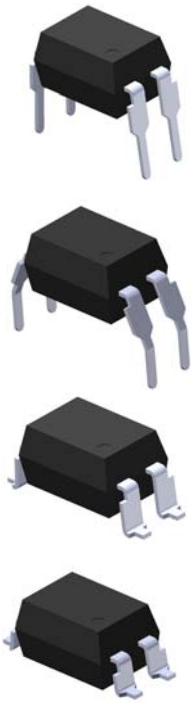
4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

EL814 Series

Features:

- AC input response
- Current transfer ratio
  (CTR: Min. 20% at I_F =±1mA ,V_{CE} =5V)
- High isolation voltage between input and output (Viso=5000 V rms)
- Wide Operating temperature range
  -55~110ºC
- High collector-emitter voltage V_{CEO}=80V
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved (No. 716108)
- NEMKO approved (No. P06206474)
- DEMKO approved (No. 313924)
- FIMKO approved (No. FI 22807)
- CSA approved (No. 1143601)



Description

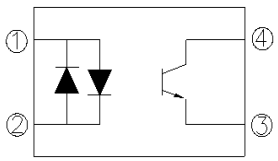
The EL814 series of devices each consist of two infrared emitting diodes, connected in inverse parallel, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- AC line monitor
- Programmable controllers
- Telephone line interface
- Unknown polarity DC sensor

Schematic



Pin Configuration
1. Anode / Cathode
2. Cathode / Anode
3. Emitter
4. Collector

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Absolute Maximum Ratings (T_a=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	±50	mA
	Peak forward current (t = 10μs)	I_{FM}	1	A
	Power dissipation	P_D	70	mW
	Derating factor (above 100 ºC)		2.9	mW/ºC
Output	Power dissipation	P_C	150	mW
	Derating factor (above 100 ºC)		5.8	mW/ºC
	Collector-Emitter voltage	V_{CEO}	80	V
	Emitter-Collector voltage	V_{ECO}	6	V
Total power dissipation		P_{tot}	200	mW
Isolation voltage *1		V_{iso}	5000	V rms
Operating temperature		T_{opr}	-55~+110	°C
Storage temperature		T_{stg}	-55~+125	°C
Soldering temperature *2		T_{sol}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

*2 For 10 seconds.

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Electrical Characteristics (T_a=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	I_F = ± 20mA
Input capacitance	C_{in}	-	50	250	pF	V = 0, f = 1KHz

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	V_{CE} = 20V, I_F = 0mA
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	I_C = 0.1mA
Emitter-Collector breakdown voltage	BV_{ECO}	6	-	-	V	I_E = 0.1mA

Transfer Characteristics (T_a=25°C unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	EL814	CTR	20	-	300	%	I_F = ±1mA ,V_{CE} = 5V
	EL814A		50	-	150		
Collector-emitter saturation voltage		$V_{CE(sat)}$	-	0.05	0.2	V	I_F = ±20mA ,I_c = 1mA
Isolation resistance		R_{IO}	5×10^{10}	10^{11}	-	Ω	V_{IO} = 500Vdc, 40~60%R.H
Cut-off frequency		f_c	-	80	-	kHz	V_{CE}=5V, I_C=2 mA, R_L=100Ω, -3dB
Floating capacitance		C_{IO}	-	0.6	1.0	pF	V_{IO} = 0, f = 1MHz
Rise time		T_r	-	7	18	μs	V_{CE}=2V, I_C=2mA,R_L=100Ω
Fall time		T_f	-	11	18	μs	

* Typical values at T_a = 25°C

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Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

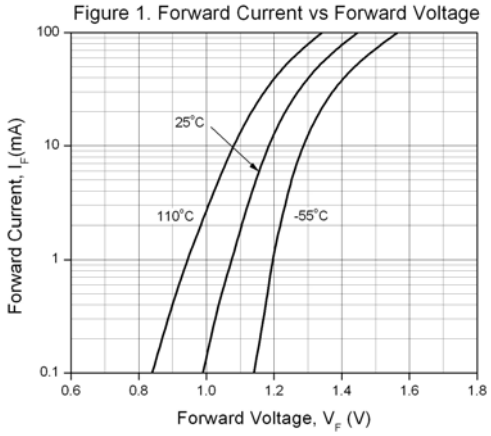

Figure 2. Normalized Current Transfer Ratio vs Forward Current

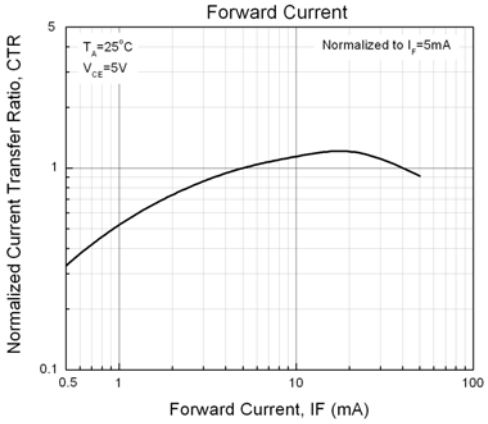

Figure 3. Current Transfer Ratio vs Ambient Temperature

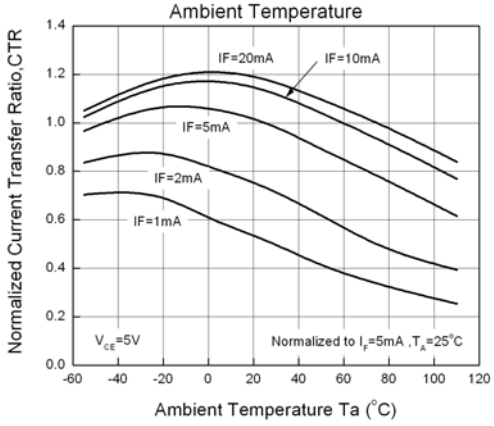

Figure 4. Dark Current vs Ambient Temperature

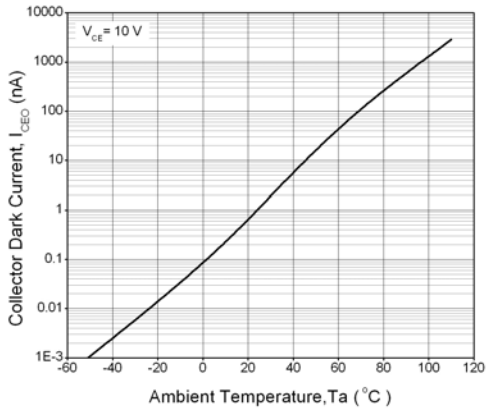

Figure 5. Collector Current vs Collector Voltage

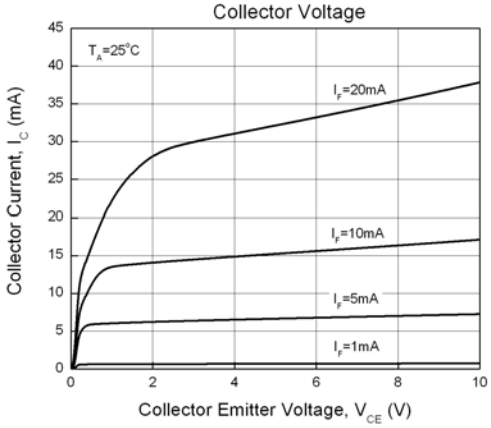

Figure 6. Collector Current vs Collector Voltage

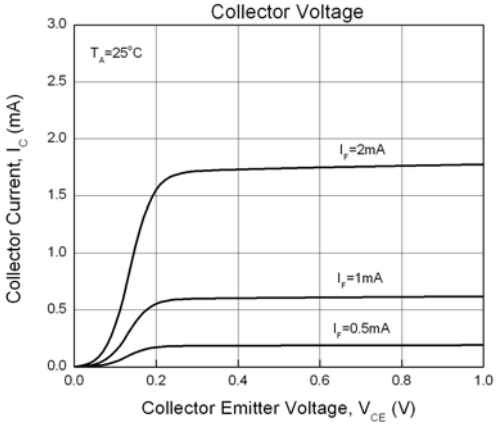

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Figure 7. Collector-Emitter Saturation Voltage vs Collector Current

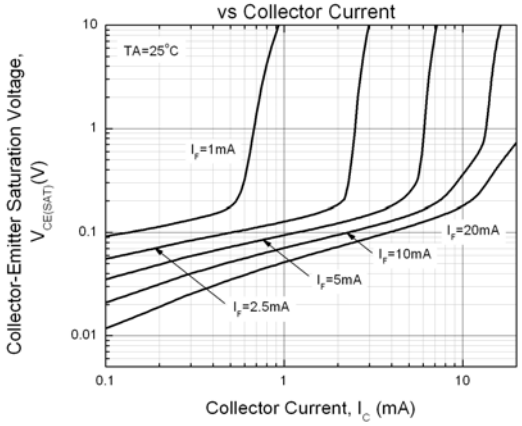
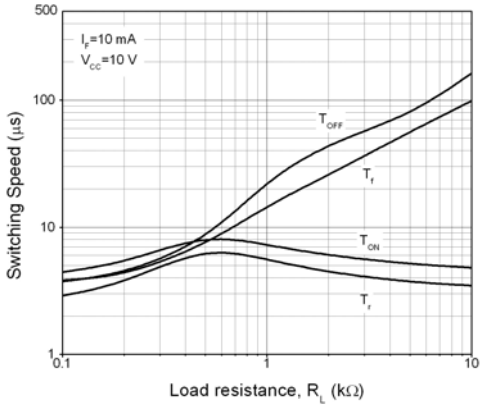


Figure 8. Switching Time vs Load Resistance



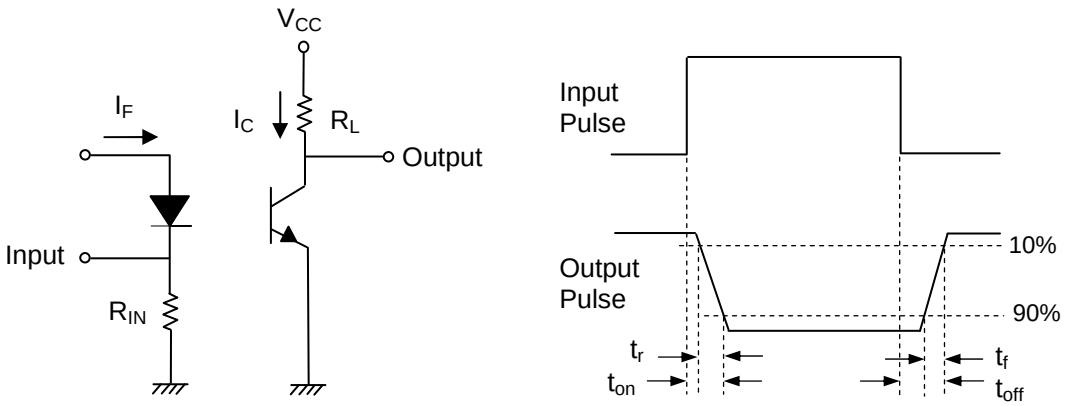


Figure 9. Switching Time Test Circuit & Waveforms

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Order Information

Part Number

EL814X(Y)(Z)

Note

X = Lead form option (S, S1, M or none)
Y = CTR Rank option (A or none)
Z = Tape and reel option (TA, TB, TU, TD or none).

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
M	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

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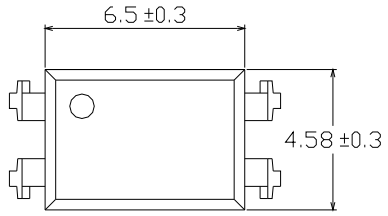
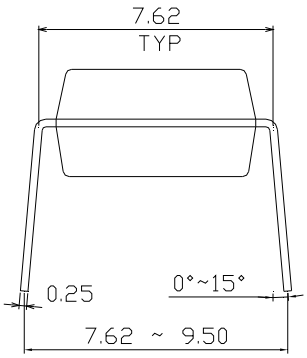
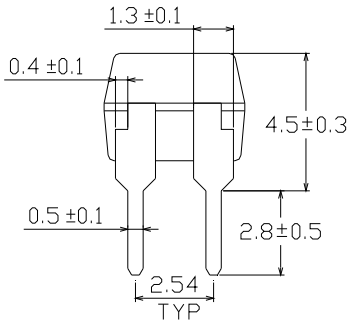
Package Drawings

(Dimensions in mm)

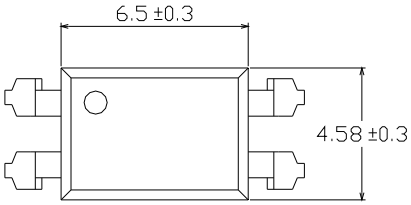
Standard DIP Type

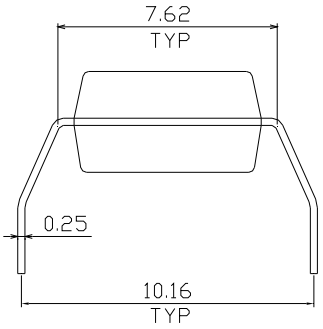


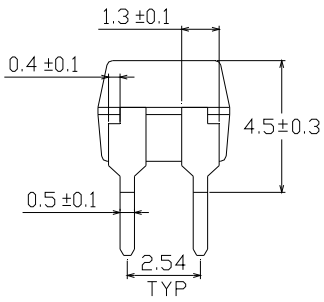




Option M Type







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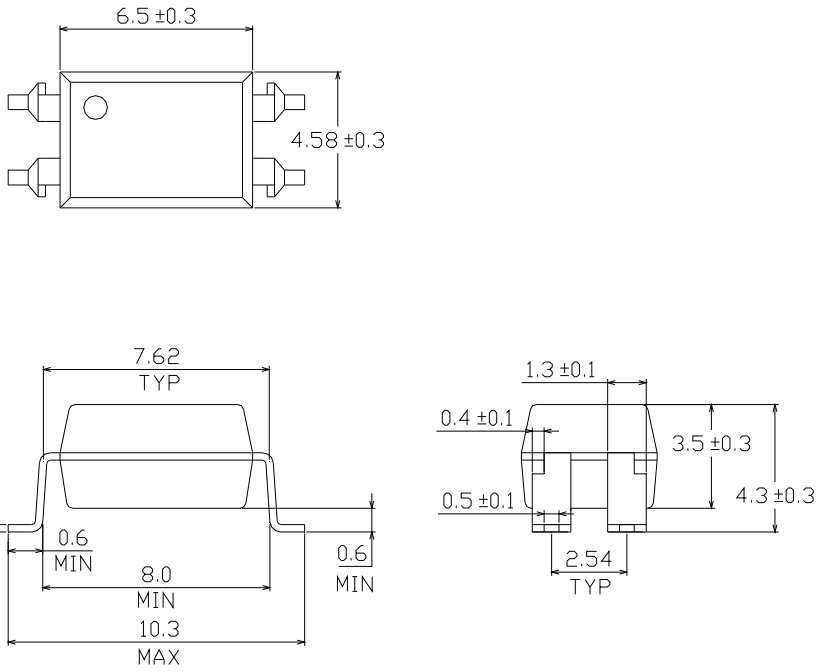
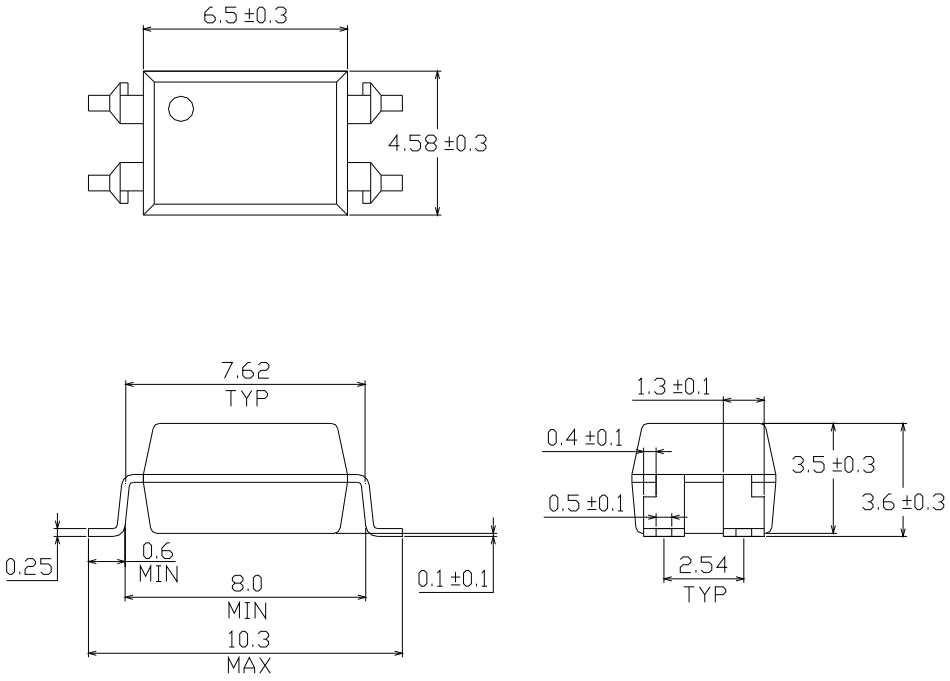
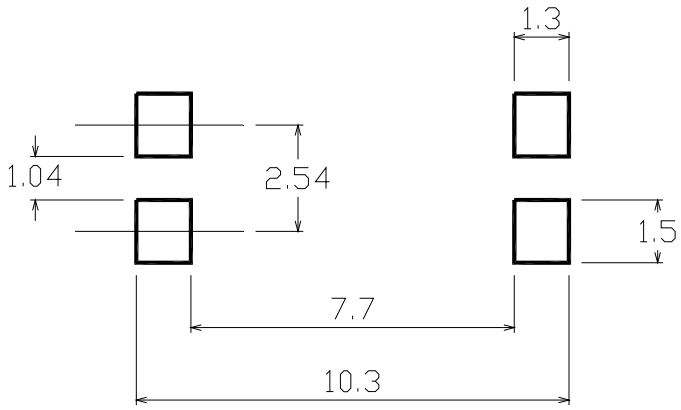
Option S Type



Option S1 Type



Recommended pad layout for surface mount leadform



Device Marking

Notes

EL814	denotes Device Number
F	denotes Factory Code (C: China, T: Taiwan)
R	denotes CTR Rank (A or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code

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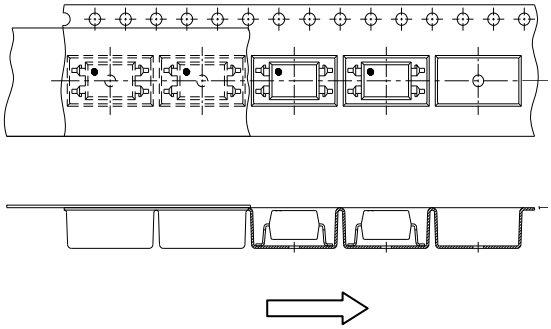
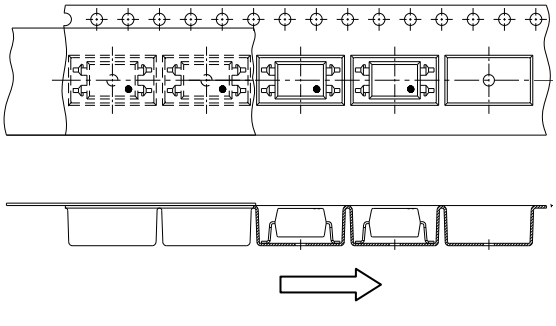
Tape & Reel Packing Specifications

Option TA



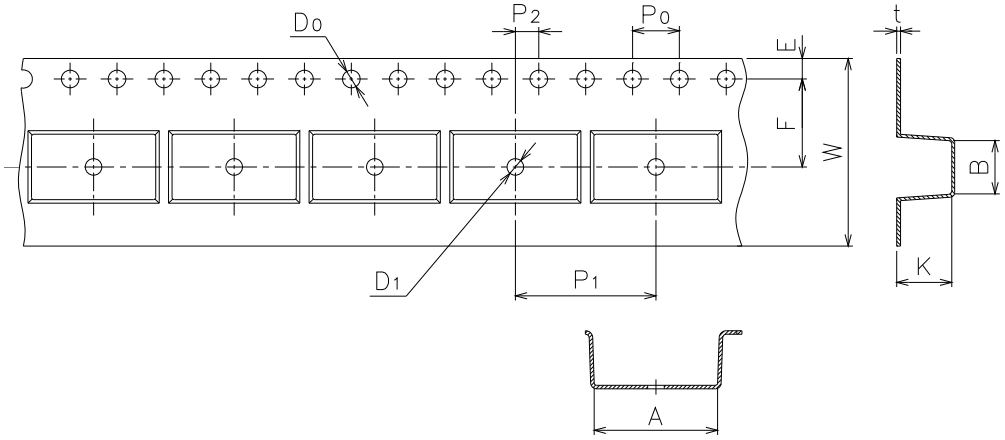
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimensions



Dimension No.	A	B	Do	D1	E	F
Dimension(mm)	10.4±0.1	4.55±0.1	1.5±0.1	1.5±0.05	1.75±0.1	7.5±0.1
Dimension No.	Po	P1	P2	t	W	K
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.1	0.33±0.1	16.0+0.3/ -0.1	4.55±0.1

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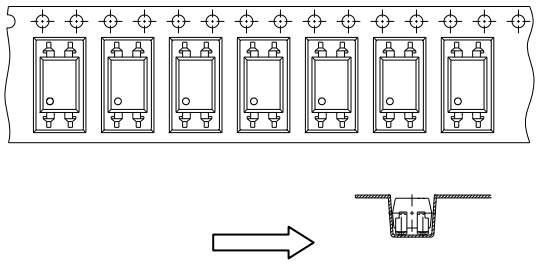
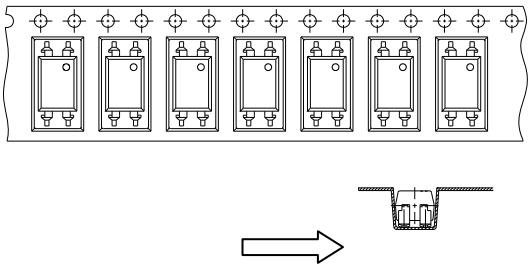
Option TD



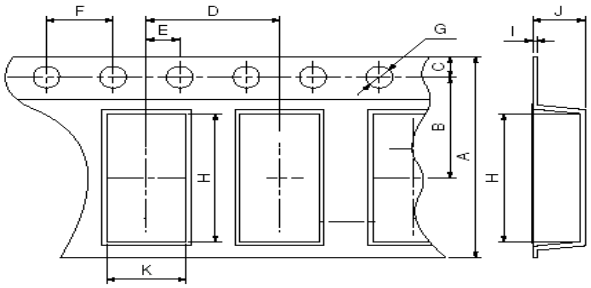
Direction of feed from reel

Option TU



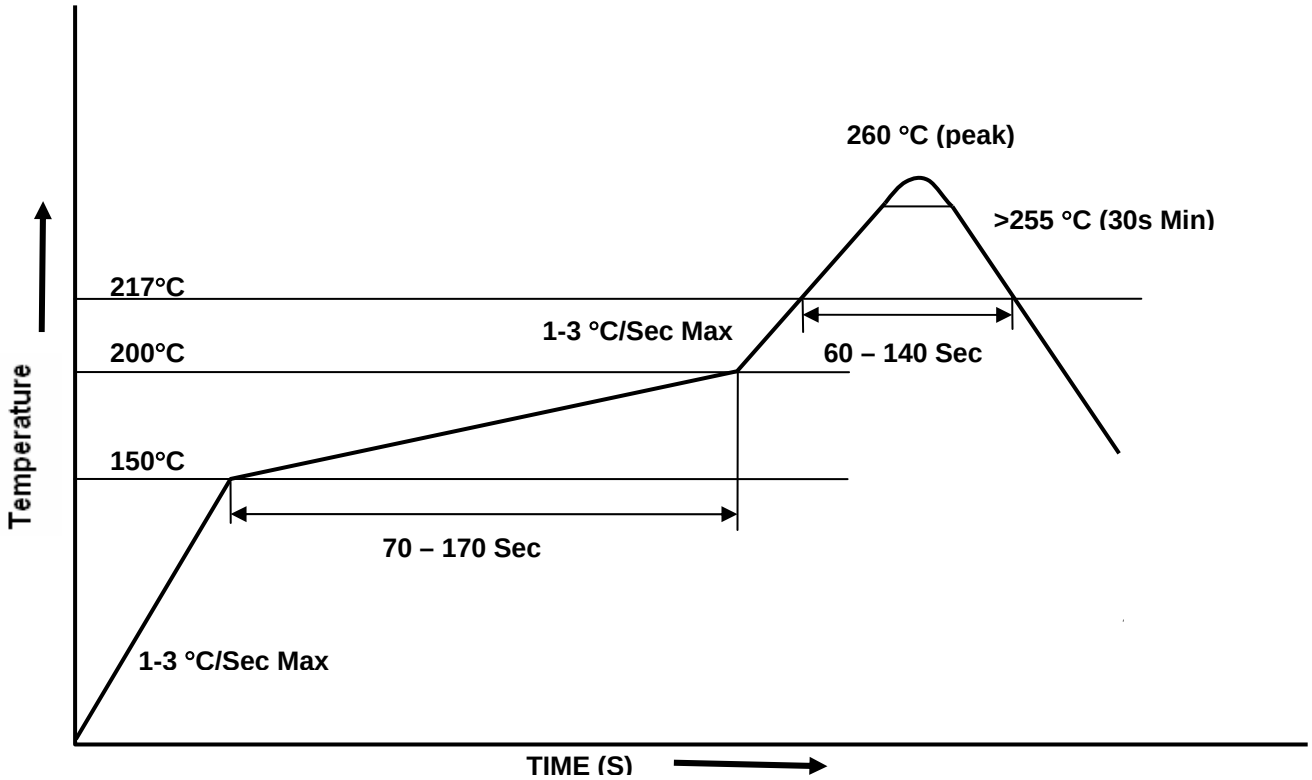
Direction of feed from reel

Tape dimensions



Dimension No.	A	B	C	D	E	F
Dimension(mm)	16.00±0.3	7.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1
Dimension No.	G	H	I	J	K	
Dimension(mm)	1.5+0.1/-0	10.4±0.1	0.4±0.05	4.55±0.1	5.1±0.1	

Solder Reflow Temperature Profile



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